KVR1066D3E7K3/3G

3GB (1GB 128M x 72-Bit x 3 pcs.) PC3-8500
CL7 ECC 240-Pin DIMM Kit

DESCRIPTION

ValueRAM's KVR1066D3E7K3/3G is a kit of three 128M x 72-bit 1GB (1024MB) DDR3-1066 CL7 SDRAM (Synchronous DRAM) ECC memory modules, based on nine 128M x 8-bit DDR3-1066 FBGA components per module. Total kit capacity is 3GB. The SPDs are programmed to JEDEC standard latency 1066Mhz timing of 7-7-7 at 1.5V. Each 240-pin DIMM uses gold contact fingers and requires +1.5V. The electrical and mechanical specifications are as follows:

FEATURES

- JEDEC standard 1.5V ± 0.075V Power Supply
- VDDQ = 1.5V ± 0.075V
- 533MHz fCK for 1066Mb/sec/pin
- 8 independent internal bank
- Programmable CAS Latency: 5,6,7,8,9,10
- Posted CAS
- Programmable Additive Latency: 0, CL - 2, or CL - 1 clock
- Programmable CAS Write Latency(CWL) = 6(DDR3-1066)
- 8-bit pre-fetch
- Burst Length: 8 (Interleave without any limit, sequential with starting address "000" only), 4 with tCCD = 4 which does not allow seamless read or write [either on the fly using A12 or MRS]
- Bi-directional Differential Data Strobe
- Internal(self) calibration : Internal self calibration through ZQ pin (RZQ : 240 ohm ± 1%)
- On Die Termination using ODT pin
- Average Refresh Period 7.8us at lower than TCASE 85°C, 3.9us at 85°C < TCASE ≤ 95°C
- Asynchronous Reset
- 1066Mbps CL7 doesn't have backward compatibility with 800Mbps CL5
- PCB : Height 1.180" (30.00mm), single sided component

SPECIFICATIONS

CL(IDD)	7 cycles
Row Cycle Time (tRCmin)	50.63ns (min.)
Refresh to Active/Refresh Command Time (tRFCmin)	110ns
Row Active Time (tRASmin)	37.5ns (min.)
Power	1.147 W (operating per module)
UL Rating	94 V - 0
Operating Temperature	0° C to 85° C
Storage Temperature	-55° C to +100° C

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MODULE DIMENSIONS:



